16-bit Bidirectional Transceivers with 3-state Outputs

HITACHI

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Description

The HD74LVCZ16245A has sixteen two direction buffers, for the fittest at two direction bus lines with three state outputs in a 48 pin package. When (DIR) is high, data flows from the A inputs to the B outputs, and when (DIR) is low, data flows from the B inputs to the A outputs. A and B bus are separated by making enable input (\overline{G}) high level.

When V_{CC} is between 0 and 1.5 V, the device is in the high impedance state during power up or power down.

Low voltage and high speed operation is suitable at battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.7 \text{ to } 5.5 \text{ V}$
- All inputs V_{IH} (Max) = 5.5 V (@ V_{CC} = 0 to 5.5 V)
- All inputs / outputs $V_{I/O}$ (Max) = 5.5 V (@ V_{CC} = 0 V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High impedance state during power up and power down
- Power off disables outputs, permitting live insertion
- High output current ± 24 mA (@V_{CC} = 3.0 to 5.5 V)



Function Table

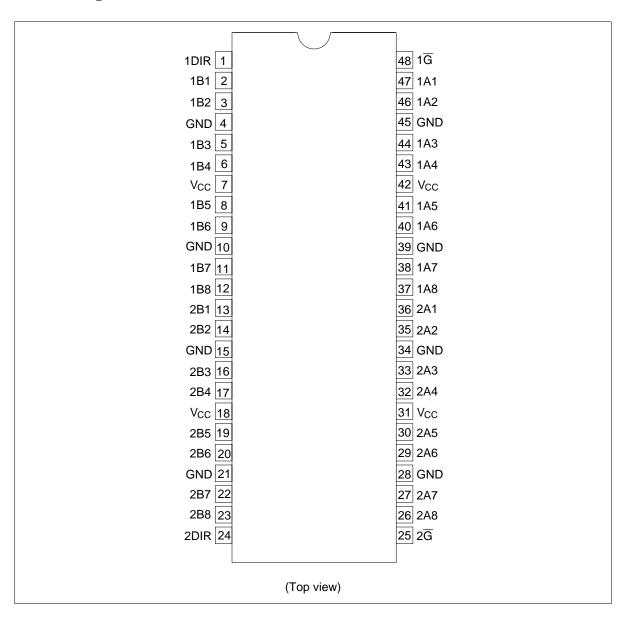
Inputs		Operation				
G	DIR					
L	L	B data to A bus				
L	Н	A data to B bus				
Н	Χ	Z				

H : High level

L : Low level X : Immaterial

Z : High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	-0.5 to 7.0	V	
Input voltage	V _i	-0.5 to 7.0	V	
Input / output voltage	$V_{I/O}$	-0.5 to 7.0	V	Output "Z" or V _{CC} : OFF
		-0.5 to V _{cc} +0.5		Output "H" or "L"
Input diode current	I _{IK}	- 50	mA	V ₁ < 0
Output diode current	I _{ok}	-50	mA	V _o < 0
Output current	Io	±50	mA	
V _{cc} , GND current	I _{CC} or I _{GND}	±100	mA	
Storage temperature	Tstg	-65 to 150	°C	

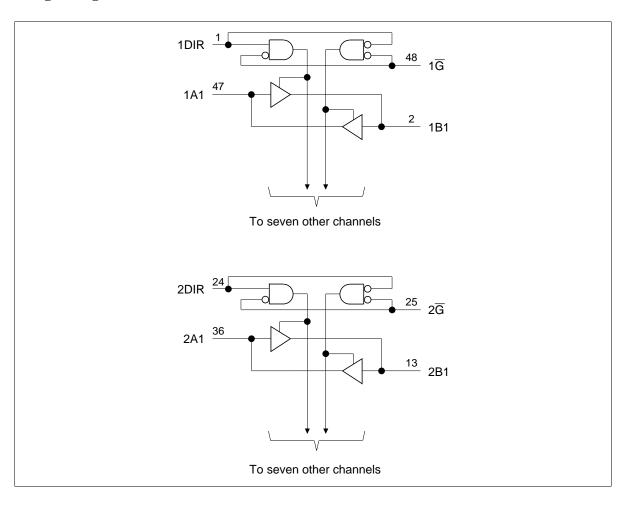
Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	2.7 to 5.5	V	At operation
Input voltage	Vı	0 to 5.5	V	
Input / output voltage	V _{I/O}	0 to 5.5	V	Output "Z" or V _{cc} : OFF
		0 to V _{cc}		Output "H" or "L"
Output current	I _{OH}	-12	mA	V _{CC} = 2.7 V
		-24 ^{*1}		$V_{\rm CC} = 3.0 \text{ to } 5.5 \text{ V}$
	I _{OL}	12		$V_{\rm CC}$ = 2.7 V
		24 *1		$V_{\rm CC}$ = 3.0 to 5.5 V
Input rise / fall time	t _r , t _f	0 to 6	ns / V	
Operating temperature	Та	-40 to +85	°C	

Note: 1. Duty cycle ≤ 50%

Logic Diagram



Electrical Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.7 to 3.6	2.0	_	_	V	
		4.5 to 5.5	V _{CC} ×0.7	_	_	_	
	V _{IL}	2.7 to 3.6	_	_	0.8	_	
		4.5 to 5.5	_	_	V _{cc} ×0.3	_	
Output voltage	V _{OH}	2.7 to 5.5	V _{CC} -0.2	_	_	V	I _{OH} = -100 μA
		2.7	2.2	_	_	=	I _{OH} = -12 mA
		3.0	2.4	_	_	=	
		3.0	2.2	_	_	-	I _{OH} = -24 mA
		4.5	3.8	_	_	=	
	V _{OL}	2.7 to 5.5	_	_	0.2	=	I _{OL} = 100 μA
		2.7	_	_	0.4	-	I _{OL} = 12 mA
		3.0	_	_	0.55	-	I _{OL} = 24 mA
		4.5	_	_	0.55	-	
Input current	I _{IN}	0 to 5.5	_	_	±5	μΑ	V _{IN} = 0 to 5.5 V
Off state output current	I _{oz}	2.7 to 5.5	_	_	±5	μΑ	V _{OUT} = 0 to 5.5 V
	I _{OZPU}	0 to 1.5	_	_	±5	-	$V_{OUT} = 0.5 \text{ to } 5.5 \text{ V},$
	I _{OZPD}	1.5 to 0	_	_	±5	-	Output enable = don't care
Output leak current	I _{OFF}	0	_	_	±5	μΑ	V_{IN} or $V_{O} = 5.5 \text{ V}$
Quiescent supply	I _{cc}	2.7 to 3.6	_	_	225	μΑ	$V_{IN} = 3.6 \text{ to } 5.5 \text{ V}^{*1}, I_{O} = 0$
current		2.7 to 5.5	_	_	350	-	$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	2.7 to 3.6	_	_	500	=	V_{IN} = one input at (V _{CC} -0.6) V, other inputs at V _{CC} or GND
Input capacitance	C _{IN}	3.3	_	4.1	_	pF	$V_{IN} = V_{CC}$ or GND
Input / output capacitance	C _{I/O}	3.3	_	9.2	_	pF	$V_{OUT} = V_{CC}$ or GND

Note: 1. This applies in the disabled state only.

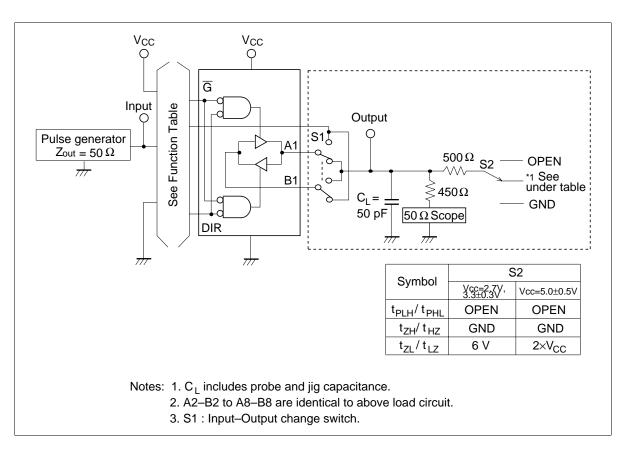
Switching Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

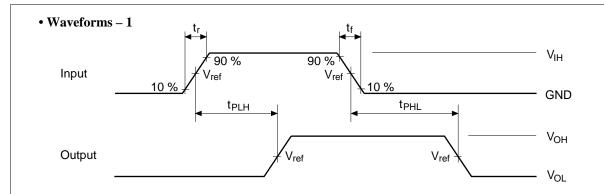
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t _{PLH}	2.7	_	_	5.2	ns	A or B	B or A
	$t_{\tiny PHL}$	3.3±0.3	1.0	_	4.6			
		5.0±0.5	_	_	4.0			
Output enable time	t_{zH}	2.7	_	_	7.3	ns	G	A or B
	$\mathbf{t}_{\scriptscriptstyleZL}$	3.3±0.3	1.5	_	6.3			
		5.0±0.5	_	_	5.2			
Output disable time	\mathbf{t}_{HZ}	2.7	_	_	7.5	ns	G	A or B
	\mathbf{t}_{LZ}	3.3±0.3	1.5	_	6.9			
		5.0±0.5	_	_	6.0			
Between output pin skew *1	toslh	2.7	_	_	_	ns		
	t_{OSHL}	3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			

Note: 1. This parameter is characterized but not tested.

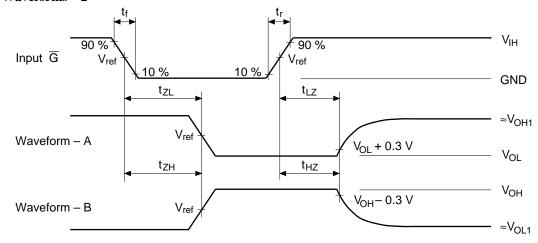
 $\mathbf{t}_{\text{OSLH}} = |\mathbf{t}_{\text{PLHm}} \!\!-\!\! \mathbf{t}_{\text{PLHn}}|, \, \mathbf{t}_{\text{OSHL}} = |\mathbf{t}_{\text{PHLm}} \!\!-\!\! \mathbf{t}_{\text{PHLn}}|$

Test Circuit





• Waveforms - 2

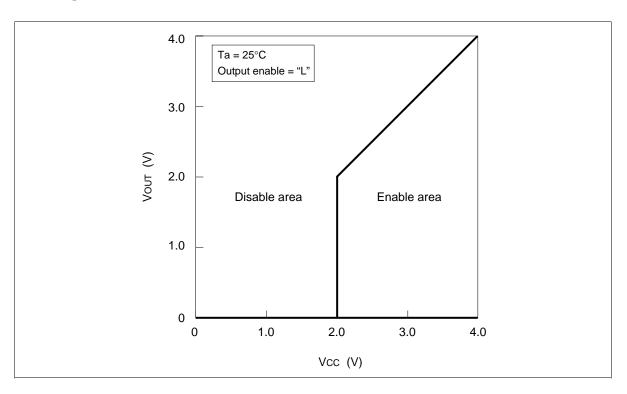


TEST	Vcc=2.7V, 3.3±0.3V	Vcc=5.0±0.5V
V _{IH}	2.7 V	V _{CC}
V _{ref}	1.5 V	50%V _{CC}
V _{OH1}	3 V	V _{CC}
V _{OL1}	GND	GND

Notes: 1. Input waveform: PRR = 10 MHz, duty cycle 50%, $t_r = 2.5$ ns, $t_f = 2.5$ ns

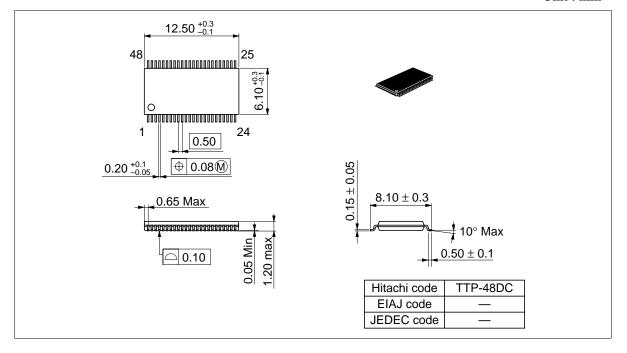
- 2. Waveform A shows input conditions such that the output is "L" level when enabled by the output control.
- 3. Waveform B shows input conditions such that the output is "H" level when enabled by the output control.

Power up / down Characteristics



Package Dimensions

Unit: mm



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